

<b>TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT</b> <b>(Under 37 CFR 1.97(b) or 1.97(c))</b>					Docket No. 050685-US
<b>Re Application Of:</b> <b>Koenenkamp</b> <small>U.S. PATENT &amp; TRADEMARK OFFICE</small>					
Application No.	Filing Date	Examiner	Customer No.	Group Art Unit	Confirmation No.
10/532,190	21 April 2005		30234		
<b>Title:</b> <b>Field Effect Transistor and Method of Its Fabrication</b>					
<b>Address to:</b> <b>Commissioner for Patents</b> <b>P.O. Box 1450</b> <b>Alexandria, VA 22313-1450</b>					
<b>37 CFR 1.97(b)</b>					
<p>1. <input checked="" type="checkbox"/> The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.</p>					
<b>37 CFR 1.97(c)</b>					
<p>2. <input type="checkbox"/> The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:</p>					
<p style="margin-left: 20px;"><input type="checkbox"/> the statement specified in 37 CFR 1.97(e);</p>					
<b>OR</b>					
<p style="margin-left: 20px;"><input type="checkbox"/> the fee set forth in 37 CFR 1.17(p).</p>					

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT  
(Under 37 CFR 1.97(b) or 1.97(c))

JUN 29 2005

Docket No.  
050685-US



Re Application  
Koenenkamp

Application No.	Filing Date	Examiner	Customer No.	Group Art Unit	Confirmation No.
10/532,190	21 April 2005		30234		

Title: Field Effect Transistor and Method of Its Fabrication

**Payment of Fee**

(Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p))

- A check in the amount of \_\_\_\_\_ is attached.
- The Director is hereby authorized to charge and credit Deposit Account No. as described below.
  - Charge the amount of \_\_\_\_\_
  - Credit any overpayment.
  - Charge any additional fee required.
- Payment by credit card. Form PTO-2038 is attached.

**WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038.**

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27 June 2005

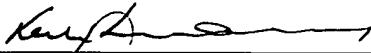
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Signature of Person Mailing Correspondence

Karl Hormann

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Typed or Printed Name of Person Mailing Certificate

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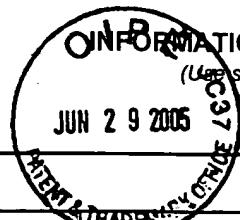
\_\_\_\_\_  
Signature

Dated: 27 June 2005

Karl Hormann  
Registration No.: 26,470

Tel.: 617-491-8867

CC:



**INFORMATION DISCLOSURE CITATION**  
(Use several sheets if necessary)

JUN 29 2005

ATTY DOCKET NO  
050685-US

APPLICATION NO  
10/532,190

APPLICANT(S)  
Koenenkamp

FILING DATE  
21 April 2005

GROUP ART UNIT

**U.S. PATENT DOCUMENTS**

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
A	6,515,325 B1	2/2003	Farnsworth et al.	257	530	

**U.S. PATENT APPLICATION PUBLICATIONS**

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
AA	2002/0001905 A1	1/3/2002	Choi et al.	438	268	
BB	2003/0132461 A1	7/17/2003	Roesner et al.	257	233	

**FOREIGN PATENT DOCUMENTS**

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
a		100 36 897 C1	1/2002	Germany	H01L	29/775		✓

**OTHER DOCUMENTS** (Including Author, Title, Date, Pertinent Pages, Etc.)

aa	Engelhardt R. et al.: Growth of Compound Semiconductors in Nanometer Sized Channels of Polymers; Mat.Res.Soc.Symp.Proc. Vol. 672 (2201) pp 08.8.1 - 08.8.6

EXAMINER

DATE CONSIDERED

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.